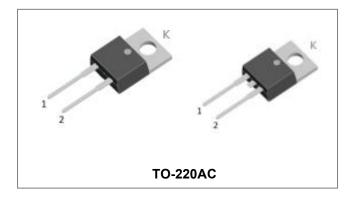


## SDUR830

Technical Data Data Sheet N1084, Rev. A

RoHS 🗭

# SDUR830 ULTRAFAST RECTIFIER



## **Circuit Diagram**



## Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: Tin Lead-free plated
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	300	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=138°C, In DC	8	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	80	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 8A, Pulse, T <sub>J</sub> = 25°C	1.01	1.3	V
	V <sub>F2</sub>	@ 8A, Pulse, T <sub>J</sub> = 125°C	0.91	1.2	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25°C	0.07	10	μA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125°C	91	500	μA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	41	45	ns

\* Pulse width < 300 µs, duty cycle < 2%

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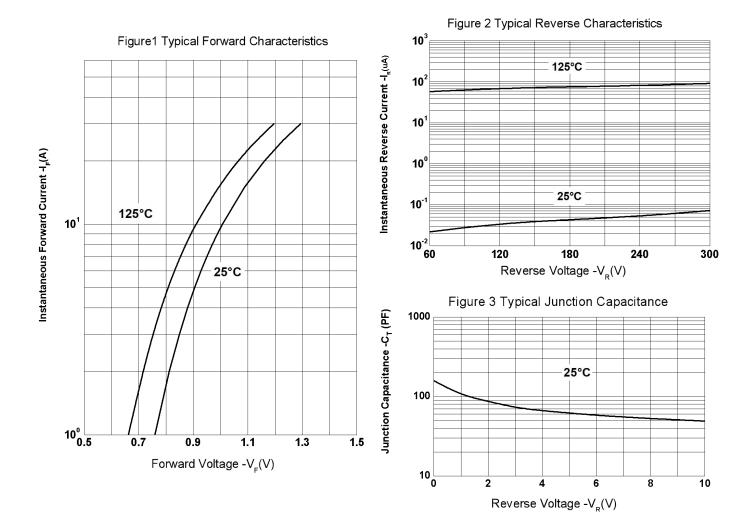
## SDUR830



### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	1.2	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

## **Ratings and Characteristics Curves**



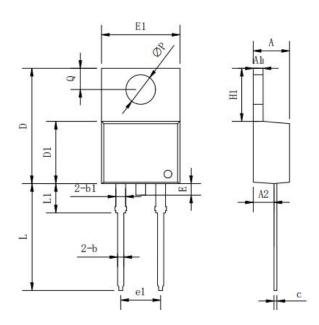


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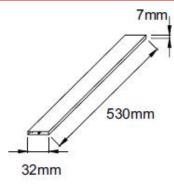


### Mechanical Dimensions TO-220AC



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	-	-	1.78
E1	9.65	10.16	10.67
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ΦΡ	-	3.56	-
Q	2.54	-	3.43

### **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

- SDUR = Device Type 8 = Forward Curre
  - = Forward Current (8A) = Reverse Voltage(300V)
- SSG = SSG

30

YY WW

L

- = Year
- = Week
  - = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

#### **Ordering Information**

Device	Package	Shipping	
SDUR830	TO-220AC (Pb-Free)	50 pcs/ tube	

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